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Kind regards,

Team Nexperia

## INTEGRATED CIRCUITS

## DATA SHEET

# **74ALVCH16825**18-bit buffer/driver (3-State)

Product specification

1998 Jul 27

IC24 Data Handbook





## 18-bit buffer/driver (3-State)

#### 74ALVCH16825

#### **FEATURES**

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A.
- CMOS low power consumption
- Direct interface with TTL levels
- Current drive ± 24 mA at 3.0 V
- MULTIBYTE<sup>TM</sup> flow-through standard pin-out architecture
- Low inductance multiple V<sub>CC</sub> and GND pins for minimum noise and ground bounce
- All data inputs have bus hold
- Output drive capability 50Ω transmission lines @ 85°C

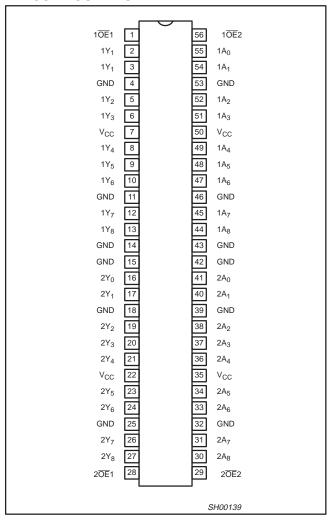
#### **DESCRIPTION**

The 74ALVCH16825 is an 18-bit non-inverting buffer/driver with 3-State outputs for bus-oriented applications.

The 74ALVCH16825 consists of two 9-bit sections with separate output enable signals. For either 9-bit buffer section, the two output enable (1<del>OE</del>1 and 1<del>OE</del>2 or 2<del>OE</del>1 and 2<del>OE</del>2) inputs must both be LOW for corresponding D outputs to be active. If either output enable input is HIGH, the outputs of that 9-buffer section are in the high impedance state.

The 74ALVCH16825 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

#### PIN CONFIGURATION



#### QUICK REFERENCE DATA

GND = 0V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER	CONDITION	TYPICAL	UNIT	
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay CP to Qn	$V_{CC} = 2.5V, C_L = 30pF$ $V_{CC} = 3.3V, C_L = 50pF$		2.0 2.0	ns
C <sub>I</sub>	Input capacitance			4.0	pF
C <sub>PD</sub>	Power dissipation capacitance per latch	$V_1 = GND \text{ to } V_{CC}^1$	Output enabled	19	pF
CPD	1 ower dissipation capacitance per laten	VI = GIVD to VCC	Output disabled	3	рі

#### NOTES:

 $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $\begin{aligned} &P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \Sigma \ (C_L \times V_{CC}{}^2 \times f_o) \ \text{where: } f_i = \text{input frequency in MHz; } C_L = \text{output load capacitance in pF;} \\ &f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V; } \Sigma \ (C_L \times V_{CC}{}^2 \times f_o) = \text{sum of outputs.} \end{aligned}$ 

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DRAWING NUMBER
56-Pin Plastic Thin Shrink Small Outline (TSSOP) Type II	–40°C to +85°C	74ALVCH16825 DGG	ACH16825 DGG	SOT364-1

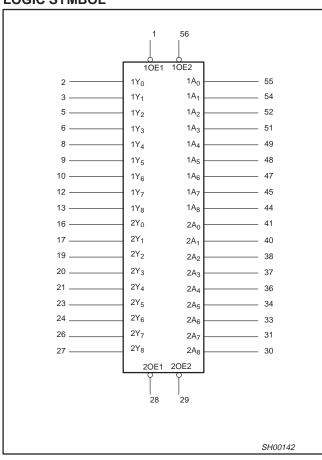
## 18-bit buffer/driver (3-State)

#### 74ALVCH16825

#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	1 <del>OE</del> 1	Output enable input
56	1 <del>OE</del> 2	(active LOW)
55, 54, 52, 51, 49, 48, 47, 45, 44	1A0 to 1A8	Data inputs
2, 3, 5, 6, 8, 9, 10, 12, 13	1Y0 to 1Y8	Data outputs
4, 11, 14, 15, 18, 25, 32, 39, 42, 43, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V <sub>CC</sub>	Positive supply voltage
28	2 <del>0E</del> 1	Output enable input
29	2 <del>OE</del> 2	(active LOW)
43, 42, 41, 40, 38, 37, 36, 34, 33, 31	2A0 to 2A8	Data inputs
16, 17, 19, 20, 21, 23, 24, 26, 27	2Y0 to 2Y8	Data outputs

#### **LOGIC SYMBOL**



#### **FUNCTION TABLE**

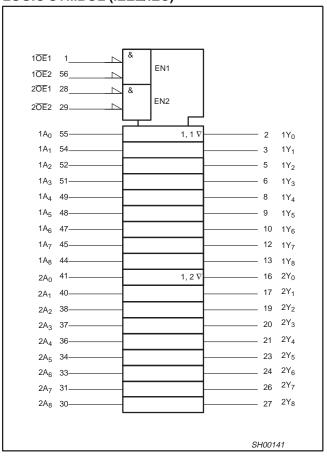
	INPUTS							
nOE1	nOE2	Α	Υ					
L	L	L	L					
L	L	Н	Н					
Н	Х	Х	Z					
Х	Н	Х	Z					

H = HIGH voltage level L = LOW voltage level

X = Don't care

Z = High impedance "off" state

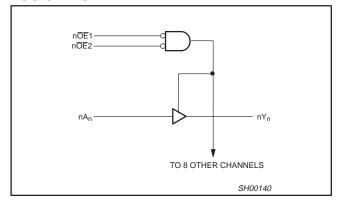
#### LOGIC SYMBOL (IEEE/IEC)



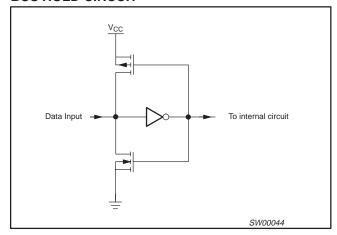
## 18-bit buffer/driver (3-State)

#### 74ALVCH16825

#### **LOGIC DIAGRAM**



#### **BUS HOLD CIRCUIT**



#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
Vcc	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	V
VI	DC Input voltage range		0	V <sub>CC</sub>	V
Vo	DC output voltage range		0	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating free-air temperature range		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 2.3 \text{ to } 3.0 \text{V}$ $V_{CC} = 3.0 \text{ to } 3.6 \text{V}$	0	20 10	ns/V

#### **ABSOLUTE MAXIMUM RATINGS**

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	<b>-</b> 50	mA
\/	DC input voltage	For control pins <sup>2</sup>	-0.5 to +4.6	V
VI	DC input voltage	For data inputs <sup>2</sup>	–0.5 to V <sub>CC</sub> +0.5	l '
I <sub>OK</sub>	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	±50	mA
V <sub>O</sub>	DC output voltage	Note 2	–0.5 to V <sub>CC</sub> +0.5	V
IO	DC output source or sink current	$V_O = 0$ to $V_{CC}$	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		± 100	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package –plastic medium-shrink (SSOP) –plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

#### NOTE:

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 18-bit buffer/driver (3-State)

## 74ALVCH16825

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp :	= -40°C to +8	5°C	UNIT
			MIN	TYP <sup>1</sup>	MAX	1
.,		V <sub>CC</sub> = 2.3 to 2.7V	1.7	1.2		,,
$V_{IH}$	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0	1.5		V
.,	1000	V <sub>CC</sub> = 2.3 to 2.7V		1.2	0.7	,,
$V_{IL}$	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V		1.5	0.8	· V
		$V_{CC} = 2.3 \text{ to } 3.6 \text{V}; V_{I} = V_{IH} \text{ or } V_{IL}; I_{O} = -100 \mu\text{A}$	V <sub>CC</sub> -0.2	V <sub>CC</sub>		
		$V_{CC} = 2.3V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -6$ mA	V <sub>CC</sub> - 0.3	V <sub>CC</sub> - 0.08		1
	V <sub>OH</sub> HIGH level output voltage	$V_{CC} = 2.3V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -12mA$	V <sub>CC</sub> - 0.6	V <sub>CC</sub> - 0.26		1 ,
VOH		$V_{CC} = 2.7V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -12mA$	V <sub>CC</sub> - 0.5	V <sub>CC</sub> - 0.14		<b>-</b>
	$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -12mA$	V <sub>CC</sub> - 0.6	V <sub>CC</sub> - 0.09			
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -24$ mA	V <sub>CC</sub> -1.0	V <sub>CC</sub> - 0.28		1
		$V_{CC} = 2.3$ to 3.6V; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 100\mu A$		GND	0.20	٧
		$V_{CC} = 2.3V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 6mA$		0.07	0.40	V
$V_{OL}$	LOW level output voltage	$V_{CC} = 2.3V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 12mA$		0.15	0.70	
		$V_{CC} = 2.7V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 12mA$		0.14	0.40	V
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 24$ mA		0.27	0.55	1
II	Input leakage current	V <sub>CC</sub> = 2.3 to 3.6V; V <sub>I</sub> = V <sub>CC</sub> or GND		0.1	5	μА
I <sub>OZ</sub>	3-State output OFF-state current	$V_{CC}$ = 2.3 to 3.6V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $V_O$ = $V_{CC}$ or GND		0.1	10	μА
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 2.3 \text{ to } 3.6 \text{V}; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		0.2	40	μΑ
Δl <sub>CC</sub>	Additional quiescent supply current	$V_{CC} = 2.3V \text{ to } 3.6V; V_I = V_{CC} - 0.6V; I_O = 0$		150	750	μΑ
I <sub>BHL</sub> <sup>2</sup>	Bus hold LOW sustaining current	$V_{CC} = 2.3V; V_I = 0.7V$	45	-		μА
IBHL	Bus floid ESVV subtaining current	$V_{CC} = 3.0V; V_I = 0.8V$	75	150		μι
I <sub>BHH</sub> <sup>2</sup>	Bus hold HIGH sustaining current	$V_{CC} = 2.3V; V_I = 1.7V$	-45 -75	475		μΑ
	Due hold LOW everdrive ever-	$V_{CC} = 3.0V; V_I = 2.0V$	-75 500	-175		
I <sub>BHLO</sub> <sup>2</sup>	Bus hold LICH eventries current	$V_{CC} = 3.6V$	500			μΑ
I <sub>BHHO</sub> <sup>2</sup>	Bus hold HIGH overdrive current	V <sub>CC</sub> = 3.6V	-500			μΑ

#### NOTES:

All typical values are at T<sub>amb</sub> = 25°C.
 Valid for data inputs of bus hold parts.

## 18-bit buffer/driver (3-State)

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#### AC CHARACTERISTICS FOR $V_{CC} = 2.3V$ TO 2.7V RANGE

 $GND = 0V; \ t_r = t_f \leq 2.0ns; \ C_L = 30pF$ 

	SYMBOL PARAMETER WAVEFORM					
SYMBOL			٧ <sub>c</sub>	UNIT		
			MIN	TYP <sup>1</sup>	MAX	
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nAn to nYn	1, 3	1.0	2.0	4.1	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-State output enable time nOEn to nYn	2, 3	1.0	2.9	6.0	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-State output disable time nOEn to nYn	2,3	1.2	2.2	5.6	ns

#### NOTE:

#### AC CHARACTERISTICS FOR $V_{CC} = 3.0V$ TO 3.6V RANGE AND $V_{CC} = 2.7V$

GND = 0V;  $t_r = t_f \le 2.5 \text{ns}$ ;  $C_L = 50 \text{pF}$ 

				LIMITS			LIMITS			
SYMBOL	PARAMETER	WAVEFORM	V <sub>C</sub>	$V_{CC} = 3.3 \pm 0.3 V$			V <sub>CC</sub> = 2.7V			
			MIN	TYP <sup>1, 2</sup>	MAX	MIN	TYP <sup>1</sup>	MAX		
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nAn to nYn	1, 3	1.0	2.0	3.4	1.0	2.1	3.9	ns	
t <sub>PZH</sub> /t <sub>PZL</sub>	3-State output enable time nOEn to nYn	2, 3	1.0	2.8	4.7	1.0	2.9	5.7	ns	
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-State output disable time nOEn to nYn	2, 3	1.3	2.9	4.5	1.3	3.0	4.9	ns	

#### NOTES:

- 1. All typical values are measured  $T_{amb} = 25$  °C.
- 2. Typical value is measured at  $V_{CC} = 3.3V$

#### AC WAVEFORMS FOR $V_{CC} = 2.3V$ TO 2.7V AND V<sub>CC</sub> < 2.3V RANGE

 $V_{M} = 0.5 V_{CC}$   $V_{X} = V_{OL} + 0.15 V$ 

 $V_Y = V_{OH} - 0.15V$   $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the

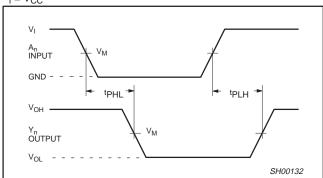
#### AC WAVEFORMS FOR $V_{CC} = 3.0V$ TO 3.6V AND $V_{CC} = 2.7V RANGE$

 $V_{M} = 1.5 \text{ V}$   $V_{X} = V_{OL} + 0.3 \text{V}$ 

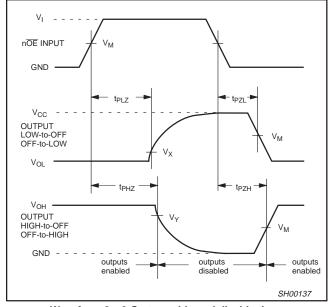
 $V_{Y} = V_{OH} - 0.3V$ 

 $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load.

 $\frac{V_{I}}{V_{I}} = 2.7V$   $\frac{V_{I}}{V_{I}} = V_{CC}$ 



Waveform 1. Input (Dn) to output (Yn) propagation delay



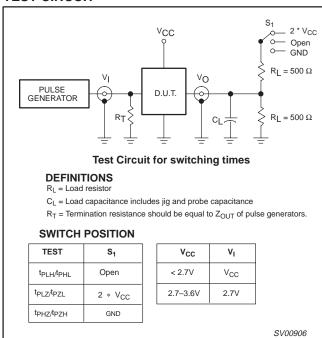
Waveform 2. 3-State enable and disable times

<sup>1.</sup> All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

## 18-bit buffer/driver (3-State)

### 74ALVCH16825

#### **TEST CIRCUIT**



Waveform 3. Load circuitry for switching times

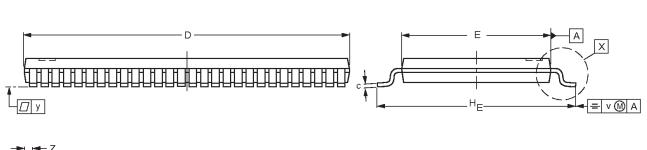
1998 Jul 27 7

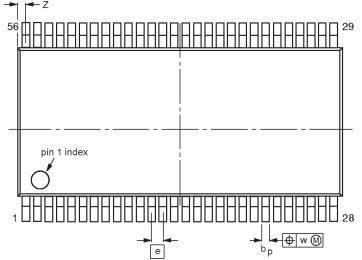
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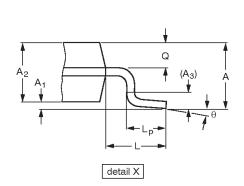
## 74ALVCH16825

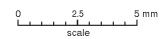
#### TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm

SOT364-1









#### DIMENSIONS (mm are the original dimensions).

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	14.1 13.9	6.2 6.0	0.5	8.3 7.9	1.0	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.5 0.1	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT364-1		MO-153EE				<del>-93-02-03-</del> 95-02-10

18-bit buffer/driver (3-State)

74ALVCH16825

**NOTES** 

## 18-bit buffer/driver (3-State)

74ALVCH16825

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

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